



Over-voltage Protection Thyristor	SP1100LB	P Series Rohs
Description		
DO-15 P Series solid state protection thyristor protect		
telecommunications equipment such as modems, line cards,		1
fax machines, and other CPE.		
P Series devices are used to enable equipment to meet		
various regulatory requirements including GR 1089, ITU		
K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968		
(formerly known as FCC Part 68).	0	

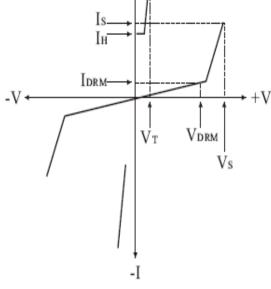
Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- · Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

Parameter	Definition	
C 0	Off-state Capacitance — typical capacitance	+I
	measured in off state	+1
di/dt	Rate of Rise of Current — maximum rated value of	Ťı
	the acceptable rate of rise in current over time	
Is	Switching Current — maximum current required to	IT
	switch to on state	
I DRM	Leakage Current — maximum peak off-state current	Is
	measured at VDRM	
\mathbf{I}^{H}	Holding Current — minimum current required to	
	maintain on state	
$\mathbf{I}^{ ext{PP}}$	Peak Pulse Current — maximum rated peak impulse	IDRM
	current	-V +
Τ	On-state Current — maximum rated continuous	
	on-state current	
I TSM	Peak One-cycle Surge Current — maximum rated	
	one-cycle AC current	
V S	Switching Voltage — maximum voltage prior to	
	switching to on state	
V DRM	Peak Off-state Voltage - maximum voltage that can	
	be applied while maintaining off state	
VF	On-state Forward Voltage — maximum forward	′ ↓
	voltage measured at rated on-state current	-I
Ϋ	On-state Voltage — maximum voltage measured at	1
	rated on-state current	





Senchip

P Series

Over-voltage		SP1100LB				ROHS		
ElectricalCha	racterist	ics						
Part Number*	Vdrm Volts	Vs Volts	Vr Volts	Idrm µ Amps	Is mAmps	It Amps	IH mAmps	Co pF
SP1100LB	90	130	4	5	800	2.2	150	40

* For surge ratings, see table below.

Notes:

• All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.

• Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Ratings Ipp Ipp Ipp IPP IPP ITSM Series 2/10 µs 8/20 µs 10/160 µs 10/560 µs 10/1000 µs di/dt 60 Hz Amps Amps Amps Amps Amps Amps Amps/µs В 250 30 500 250 150 100 80

Thermal Considerations

Package DO-15	Symbol	Parameter	Value	Unit
	TJ	Operating Junction Temperature	-40 to +150	°C
	Ts	Storage Temperature Range	-40 to +150	°C
	$R_{\theta JA}$	Junction to Ambient on printed circuit	90	°C/W

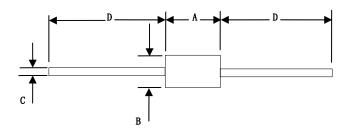


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P Series



Dimensions



Dimension	Inches		Millimeters		NOTE
Dimension	MIN	MAX	MIN	MAX	NOTE
Α	0.230	0.300	5.80	7.60	
В	0.104	0.140	2.60	3.60	Φ
С	0.026	0.034	0.70	0.90	Φ
D	1.000		25.40		



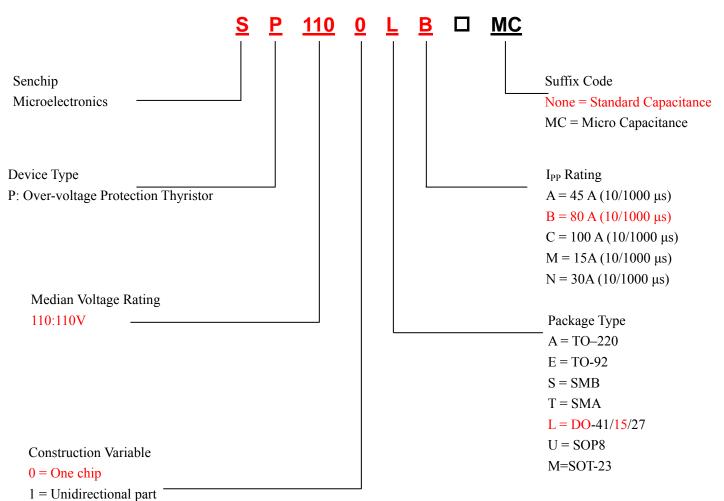
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Description of Part Number



- 2 =Two chips
- 3 = Three chips



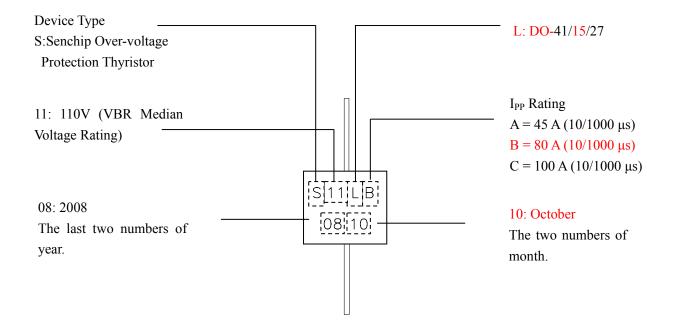
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SP1100LB

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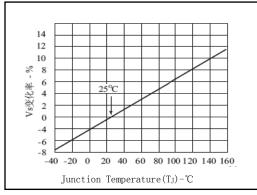
Description of Marking





Senchip	P Series		
Over-voltage Protec	tion Thyristor	SP1100LB	ROHS
Summary of Packing	Options		
Package Type	Description	Packing Quantity	Industry Standard
D0-15	Embossed Carrier Reel Pack	2000 PCS	EIA RS-481

Thermal Derating Curves



Normalized VS Change versus Junction Temperature

